

PMBD7000

Double high-speed switching diode Rev. 4 — 16 September 2010

Product data sheet

1. **Product profile**

1.1 General description

The PMBD7000 consists of two high-speed switching diodes connected in series, fabricated in planar technology, and encapsulated in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Repetitive peak forward current: $I_{FRM} \le 450 \text{ mA}$
- Small SMD plastic package
- Reverse voltage: V_R ≤ 100 V
- Repetitive peak reverse voltage: $V_{RRM} \le 100 \text{ V}$
- AEC-Q101 qualified

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	V _R = 100 V	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



Double high-speed switching diode

2. Pinning information

Table 2. Pinning

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2	1 2
			006aaa763

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMBD7000	-	plastic surface-mounted package; 3 leads	SOT23		

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PMBD7000	*5C

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

Double high-speed switching diode

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	100	V
I _F	forward current		<u>[1]</u> _	215	mA
			[2] -	125	mA
I _{FRM}	repetitive peak forward current		-	450	mA
I _{FSM}	non-repetitive peak forward current	square wave	<u>[3]</u>		
		$t_p = 1 \mu s$	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1][4]</u> _	250	mW
Per device					
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		–55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Single diode loaded.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2] -	-	500	K/W
R _{th(j-t)}	thermal resistance from junction to tie-point		-	-	360	K/W

^[1] Single diode loaded.

^[2] Double diode loaded.

^[3] $T_j = 25$ °C prior to surge.

^[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

Double high-speed switching diode

7. Characteristics

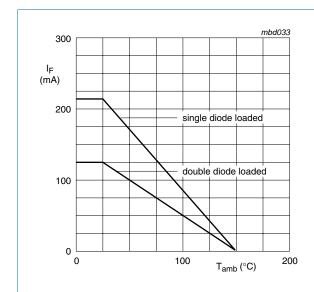
Table 7. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	Э					
V_{F}	forward voltage	I _F = 1 mA	-	550	700	mV
		I _F = 10 mA	-	670	820	mV
		$I_F = 50 \text{ mA}$	-	-	1	V
		I _F = 100 mA	-	0.75	1.1	V
		I _F = 150 mA	-	-	1.25	V
I _R reverse current	reverse current	$V_R = 50 \text{ V}$	-	-	300	nΑ
		V _R = 100 V	-	-	500	nΑ
		$V_R = 50 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		[1] -	-	4	ns
V_{FR}	forward recovery voltage	Э	[2] _	-	1.75	V

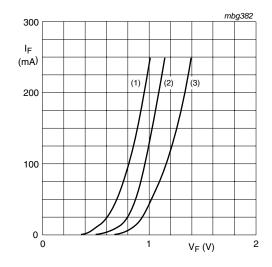
^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

^[2] When switched from $I_F = 10$ mA; $t_r = 20$ ns.



FR4 PCB, standard footprint

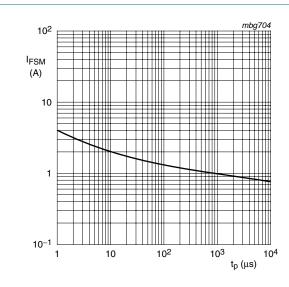
Fig 1. Forward current as a function of ambient temperature; derating curve



- (1) $T_j = 150 \,^{\circ}\text{C}$; typical values
- (2) $T_j = 25 \,^{\circ}C$; typical values
- (3) $T_j = 25$ °C; maximum values

Fig 2. Forward current as a function of forward voltage

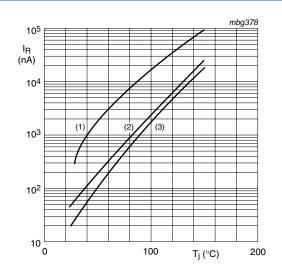
Double high-speed switching diode



Based on square wave currents.

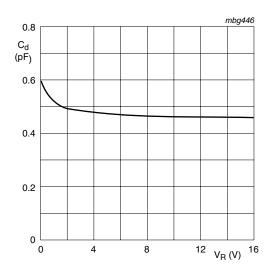
 $T_j = 25$ °C; prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $V_R = 50 \text{ V}$; maximum values
- (2) $V_R = 30 \text{ V}$; typical values
- (3) $V_R = 50 \text{ V}$; typical values

Fig 4. Reverse current as a function of junction temperature

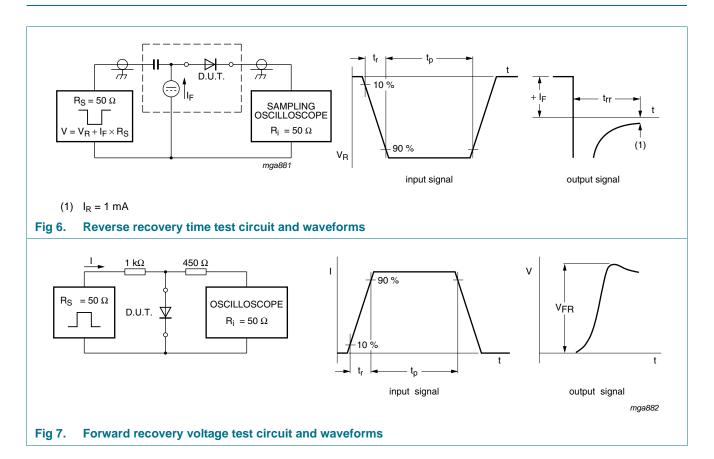


 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$

Fig 5. Diode capacitance as a function of reverse voltage; typical values

Double high-speed switching diode

8. Test information

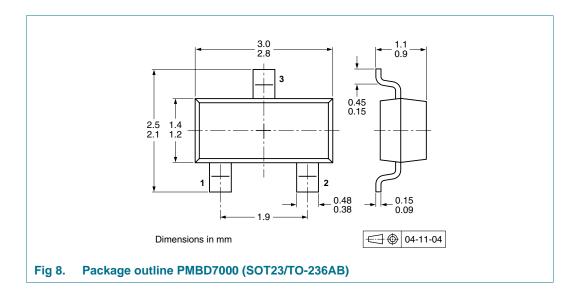


8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Double high-speed switching diode

9. Package outline



10. Packing information

Table 8. Packing methods

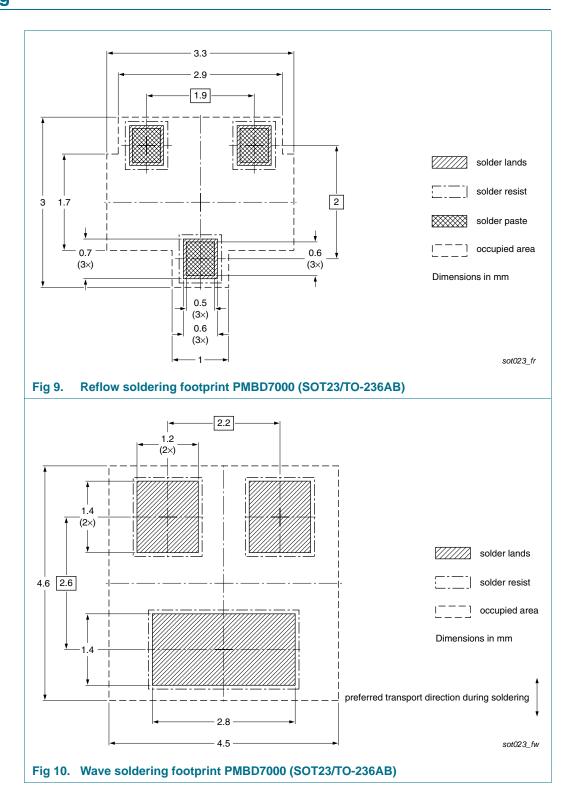
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMBD7000	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

^[1] For further information and the availability of packing methods, see Section 14.

Double high-speed switching diode

11. Soldering



Double high-speed switching diode

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PMBD7000 v.4	20100916	Product data sheet	-	PMBD7000_3			
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	 Legal texts h 	ave been adapted to the new	company name whe	re appropriate.			
	 Table 4 "Mar 	king codes": updated					
	• Table 7 "Cha	racteristics": corrected V _F uni	t for condition $I_F = 15$	0 mA			
	• Figure 2: updated						
	 Section 8 "Test information": figure title of Figure 6 amended 						
	Section 8.1 "Quality information": added						
	 Section 13 "I 	<u>egal information</u> ": updated					
PMBD7000_3	19990511	Product specification	-	PMBD7000_2			
PMBD7000_2	19960918	Product specification	-	PMBD7000_1			
PMBD7000_1	19960419	Product specification	-	-			

Double high-speed switching diode

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PMBD7000

Double high-speed switching diode

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Double high-speed switching diode

15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values
6	Thermal characteristics 3
7	Characteristics 4
8	Test information 6
8.1	Quality information 6
9	Package outline
10	Packing information 7
11	Soldering 8
12	Revision history 9
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks11
14	Contact information 11
15	Contents 12

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